To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

Phase-out/Discontinued

μPA1709

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

DESCRIPTION

This product is N-Channel MOS Field Effect Transistor designed for DC/DC converters and power management switch.

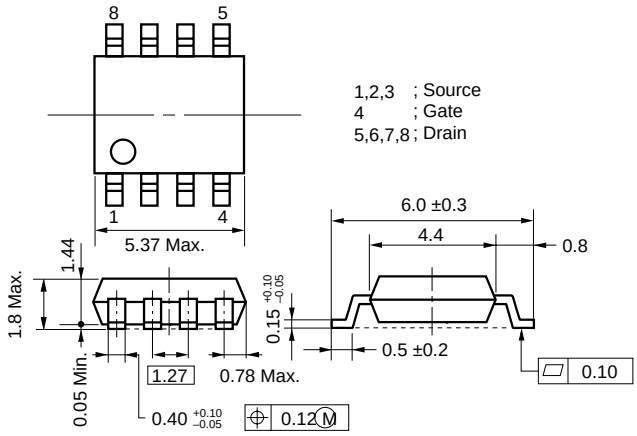
FEATURES

- Low on-resistance
  $R_{DS(on)1}$ = 9.3 mΩ (TYP.) (V_{GS} = 10 V, I_D = 4.5 A)
  $R_{DS(on)2}$ = 13.8 mΩ (TYP.) (V_{GS} = 4.5 V, I_D = 4.5 A)
- Low C_{iss} : C_{iss} = 1850 pF (TYP.)
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1709G	Power SOP8

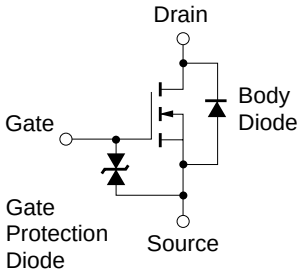
PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	40	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±25	V
Drain Current (DC)	$I_{D(DC)}$	±9.0	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	±36	A
Total Power Dissipation (T_A = 25°C) Note2	P_T	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to + 150	°C

EQUIVARENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1 %

2. Mounted on ceramic substrate of 1200 mm^2 x 0.7 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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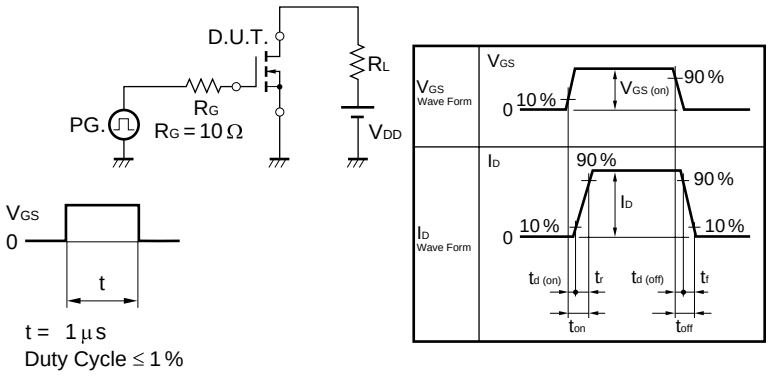
Date Published May 2001 NS CP(K)
Printed in Japan

The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS (T_A = 25 °C, All terminals are connected.)

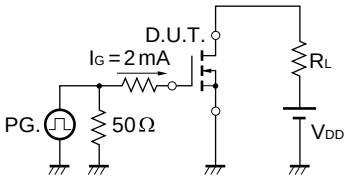
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = 10 V, I_D = 4.5 A		9.3	12.5	mΩ
	$R_{DS(on)2}$	V_{GS} = 4.5 V, I_D = 4.5 A		13.8	20.0	mΩ
Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 4.5 A	8.0	14		S
Drain Leakage Current	I_{DSS}	V_{DS} = 40 V, V_{GS} = 0 V			10	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = ±25 V, V_{DS} = 0 V			±10	μA
Input Capacitance	C_{iss}	V_{DS} = 10 V V_{GS} = 0 V f = 1 MHz		1850		pF
Output Capacitance	C_{oss}			790		pF
Reverse Transfer Capacitance	C_{rss}			330		pF
Turn-on Delay Time	$t_{d(on)}$	I_D = 4.5 A $V_{GS(on)}$ = 10 V V_{DD} = 20 V R_G = 10 Ω		27		ns
Rise Time	t_r			95		ns
Turn-off Delay Time	$t_{d(off)}$			110		ns
Fall Time	t_f			70		ns
Total Gate Charge	Q_G	I_D = 9.0 A V_{DD} = 32 V V_{GS} = 10 V		43.0		nC
Gate to Source Charge	Q_{GS}			6.0		nC
Gate to Drain Charge	Q_{GD}			14.0		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 9.0 A, V_{GS} = 0 V		0.78		V
Reverse Recovery Time	t_{rr}	I_F = 9.0 A, V_{GS} = 0 V di/dt = 100 A/μs		47		ns
Reverse Recovery Charge	Q_{rr}			44		nC

TEST CIRCUIT 1 SWITCHING TIME



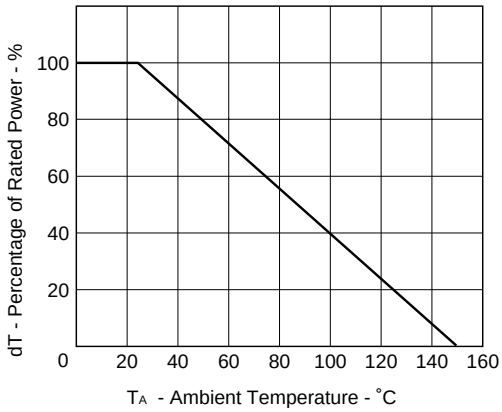
t = 1 μs
Duty Cycle ≤ 1 %

TEST CIRCUIT 2 GATE CHARGE

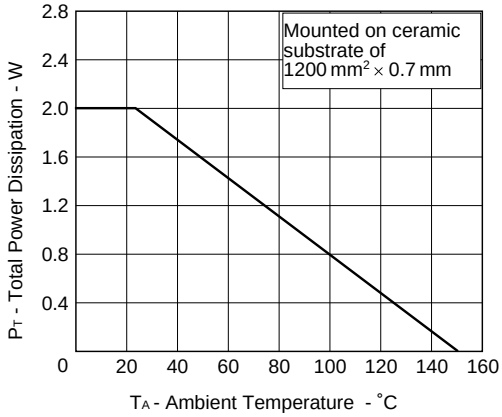


TYPICAL CHARACTERISTICS (T_A = 25 °C)

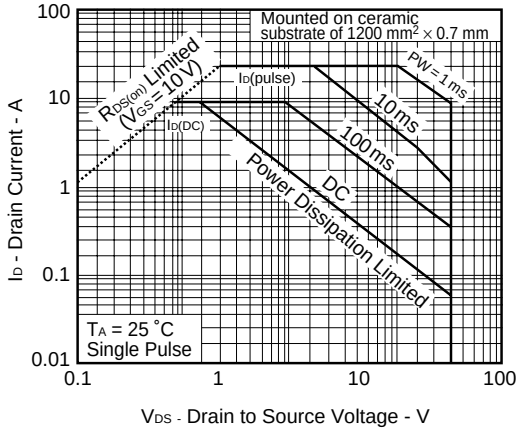
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



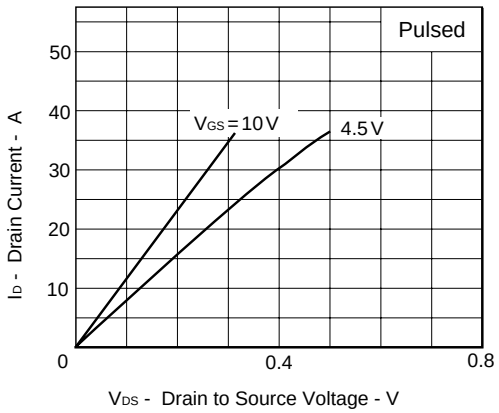
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



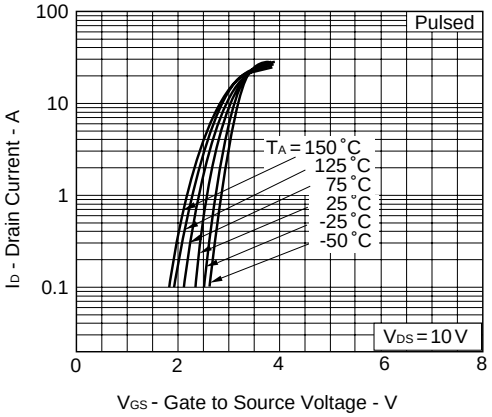
★ FORWARD BIAS SAFE OPERATING AREA



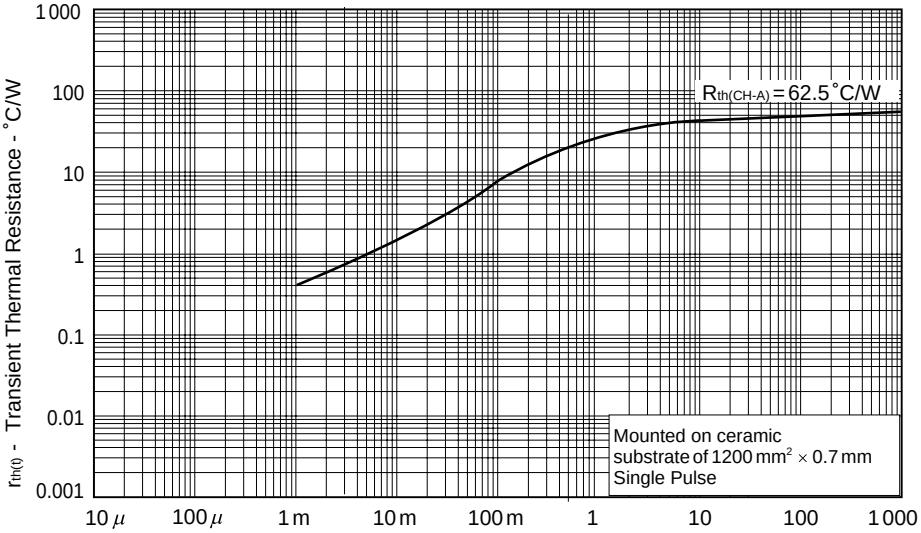
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



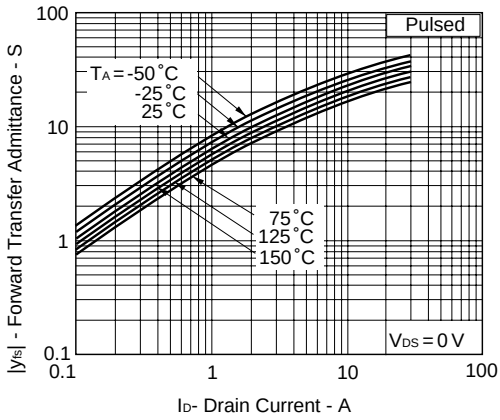
FORWARD TRANSFER CHARACTERISTICS



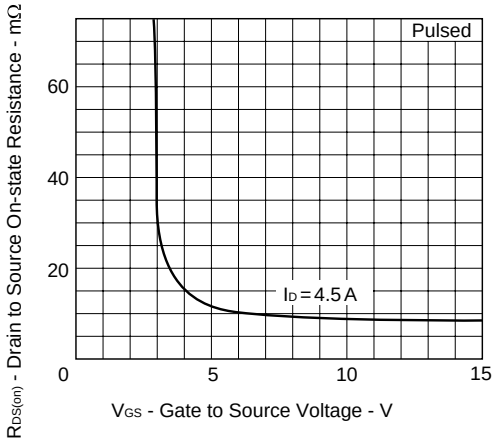
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



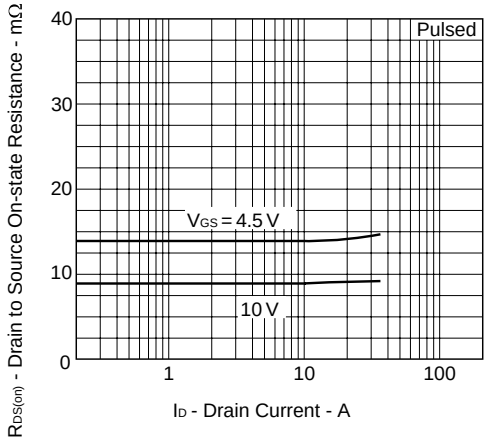
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



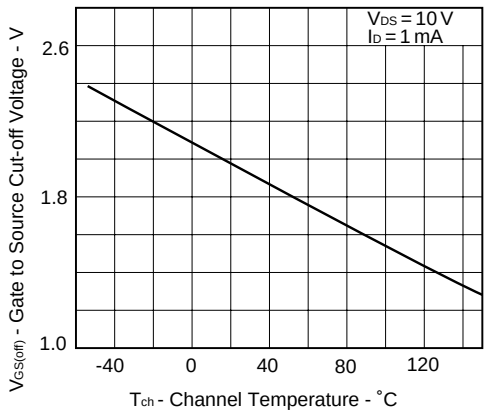
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



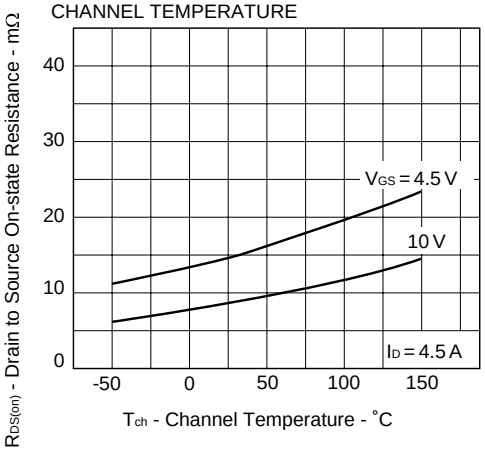
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



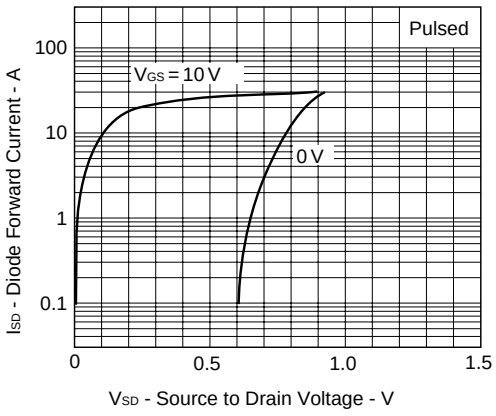
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



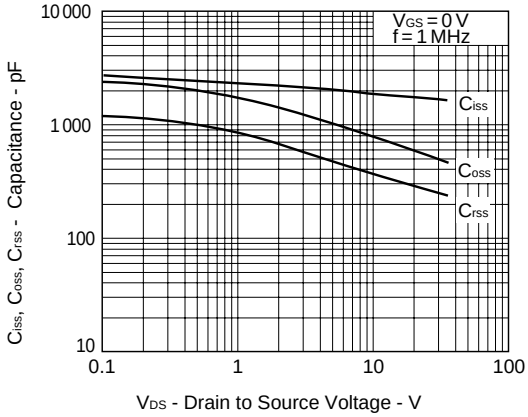
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



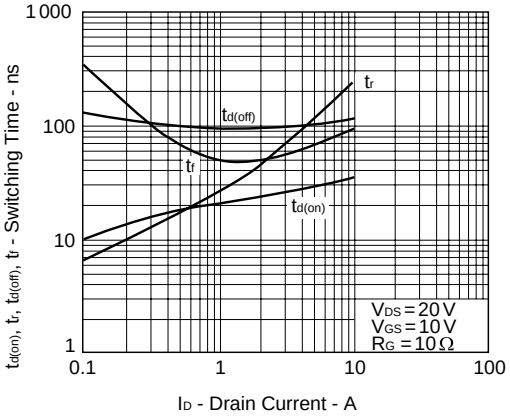
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



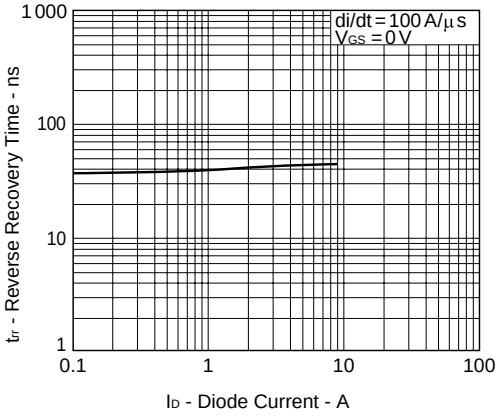
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



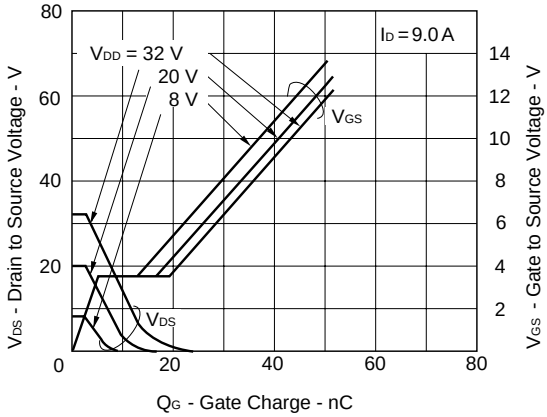
SWITCHING CHARACTERISTICS



REVERSE RECOVERY TIME vs. DIODE CURRENT



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



[MEMO]

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